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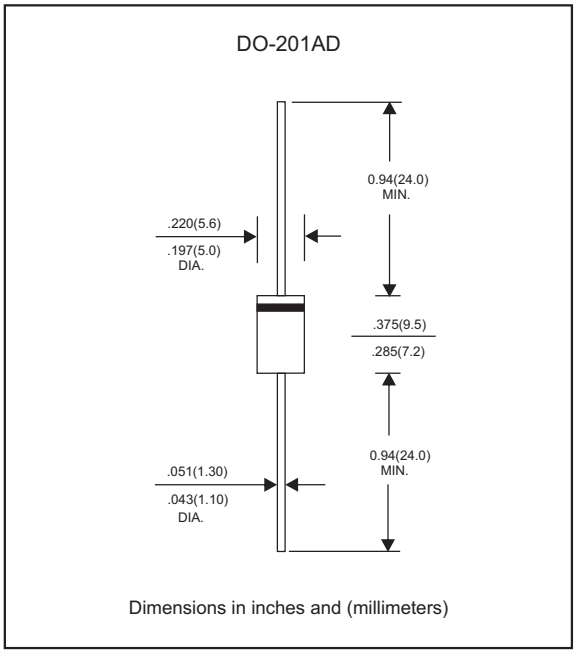
SR320 THRU SR3200

3.0A Axial Leaded Schottky Barrier Rectifiers - 20V-200V

Features

- Axial lead type devices for through hole design
- Low power loss, high efficiency.
- High current capability, low forward voltage drop.
- High surge capability.
- Guardring for overvoltage protection.
- Ultra high-speed switching.
- Silicon epitaxial planar chip, metal silicon junction.
- Lead-free parts meet environmental standards of MIL-STD-19500 /228
- Suffix"-H" for Halogen-free part, ex.SR320-H

Package outline



Mechanical data

- Epoxy : UL94-V0 rated flame retardant
- Case : Molded plastic, DO-201AD
- Lead : Axial leads, solderable per MIL-STD-202, Method 208 guranteed
- Polarity: Color band denotes cathode end
- Mounting Position : Any

Maximum ratings and Electrical Characteristics (AT T_A=25°C unless otherwise noted)

PARAMETER	CONDITIONS	Symbol	MIN.	TYP.	MAX.	UNIT
Forward rectified current	See Fig.2	I_O			3.0	A
Forward surge current	8.3ms single half sine-wave (JEDEC methode)	I_{FSM}			80	A
Reverse current	V_R = V_{RRM} T_J = 25°C	I_R			0.5	mA
	V_R = V_{RRM} T_J = 100°C				30	
Thermal resistance	Junction to ambient Junction to lead	$R_{\theta JA}$ $R_{\theta JL}$		40 10		°C/W °C/W
Diode junction capacitance	f=1MHz and applied 4V DC reverse voltage	C_J		250		pF
Storage temperature		T_{STG}	-55		+150	°C

SYMBOLS	V_{RRM} *1 (V)	V_{RMS} *2 (V)	V_R *3 (V)	V_F *4 (V)	Operating temperature T_J, (°C)
SR320	20	14	20	0.55	-55 to +125
SR340	40	28	40		
SR345	45	32	45		
SR350	50	35	50	0.70	-55 to +150
SR360	60	42	60		
SR380	80	56	80	0.85	
SR3100	100	70	100		
SR3150	150	105	150	0.92	
SR3200	200	140	200		

*1 Repetitive peak reverse voltage

*2 RMS voltage

*3 Continuous reverse voltage

*4 Maximum forward voltage@I_F=3.0A

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Rating and characteristic curves

FIG.1-TYPICAL FORWARD CURRENT DERATING CURVE

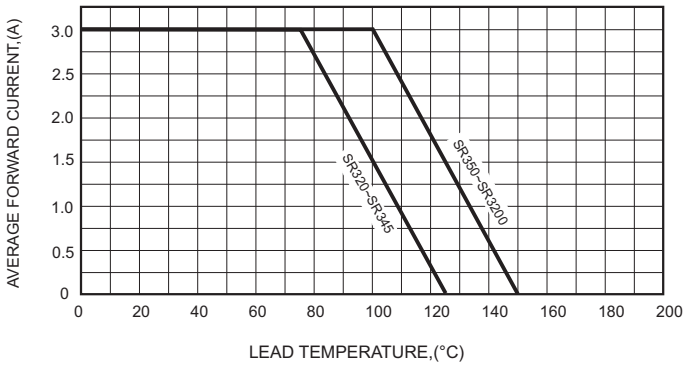


FIG.2-TYPICAL FORWARD CHARACTERISTICS

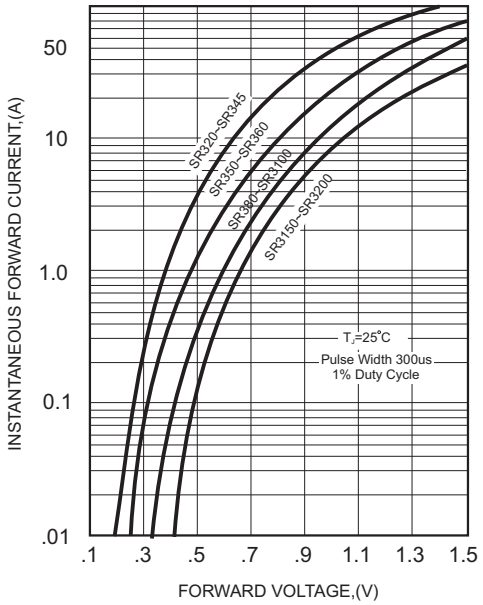


FIG.3-MAXIMUM NON-REPETITIVE FORWARD SURGE CURRENT

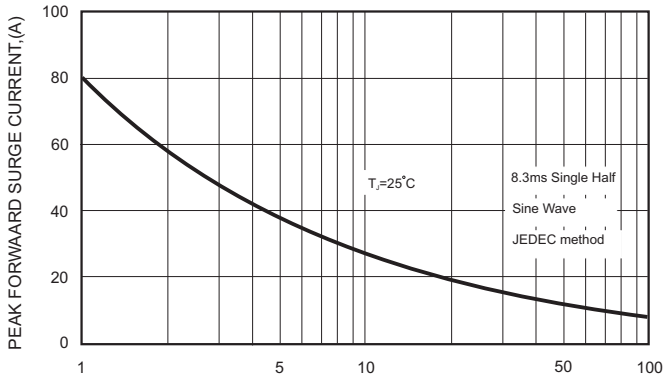


FIG.4-TYPICAL JUNCTION CAPACITANCE

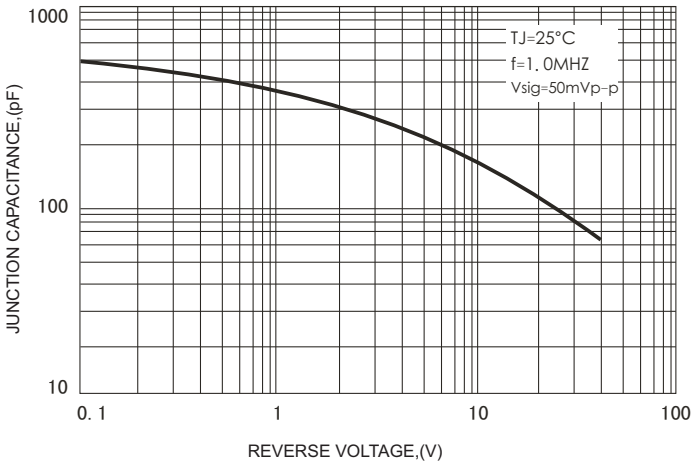
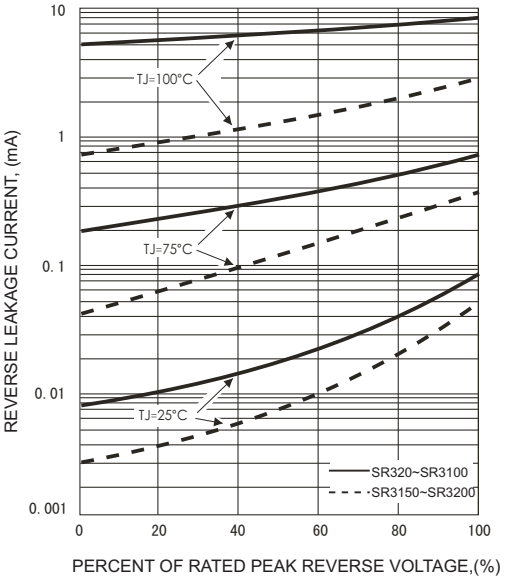


FIG.5 - TYPICAL REVERSE CHARACTERISTICS



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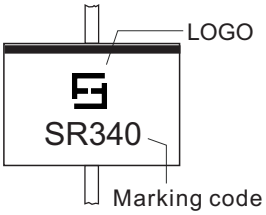
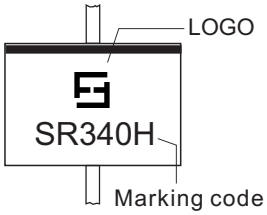
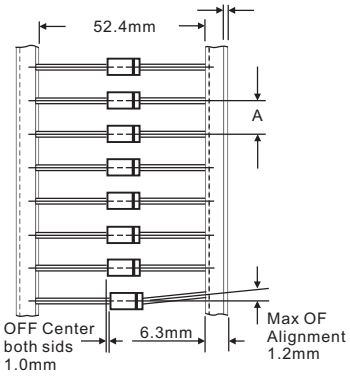
Pinning information

Pin	Simplified outline	Symbol
Pin1 cathode Pin2 anode		

Marking

Type number	Marking code	Example	
SR320 SR330 SR340 SR350 SR360 SR380 SR3100 SR3150 SR3200	SR320 SR330 SR340 SR350 SR360 SR380 SR3100 SR3150 SR3200	For Halogen Device 	For Halogen-free Device 

Taping specifications for AXIAL devices

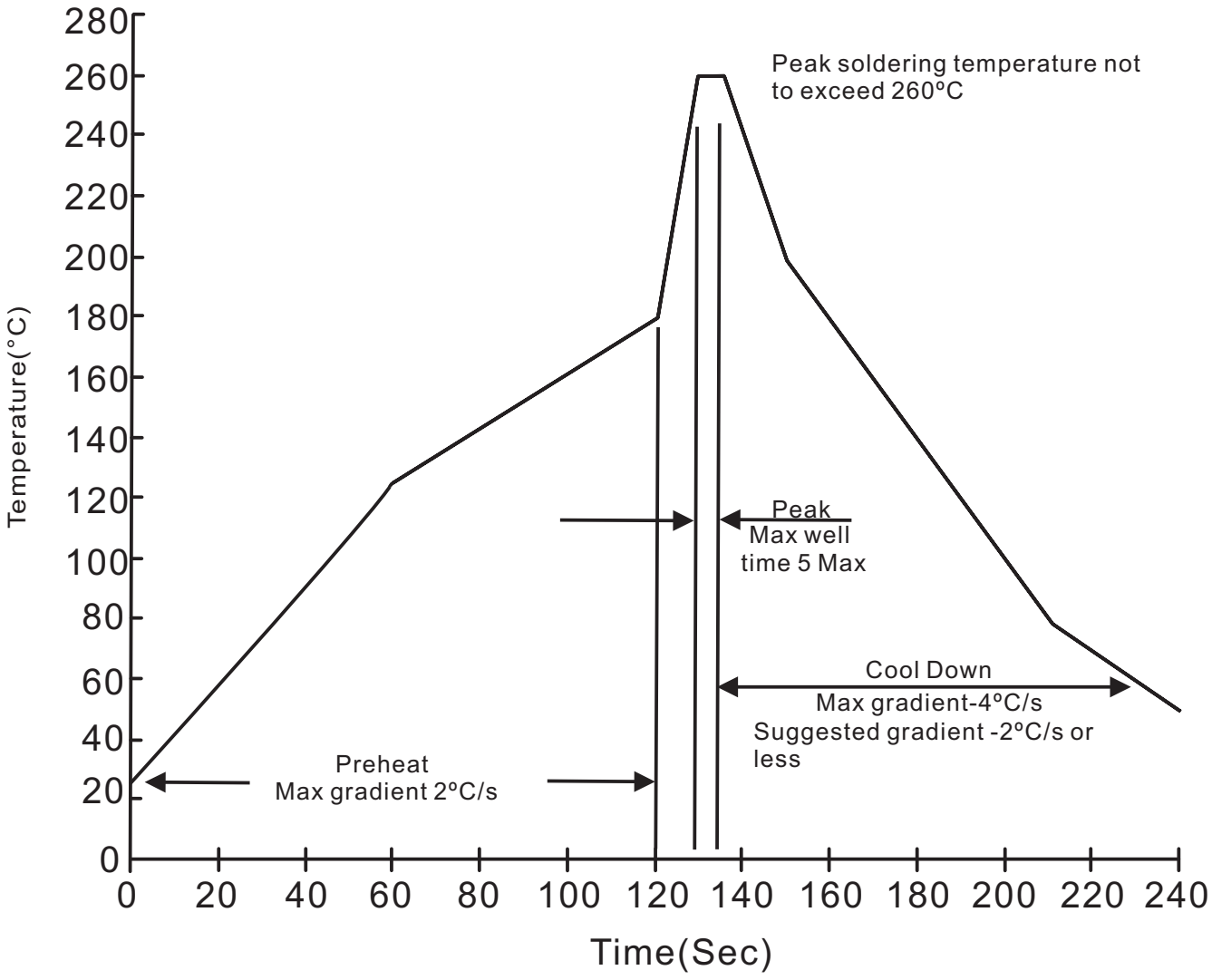


AMMO PACKING

DEVICE CASE TYPE	Q'TY 1 (PCS / BOX)	INNER BOX SIZE (m/m)	CARTON SIZE (m/m)	Q'TY 2 (PCS / CARTON)	APPROX. CROSS WEIGHT(kg)
DO-201AD	1,250	258 * 75 * 143	405 * 270 * 320	12,500	14.0

Suggested thermal profiles for soldering processes

1.Lead free temperature profile wave-soldering



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